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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Applicant: El-Kareh et al.

Art Unit: 2818

Serial No.: 10/822,078

Examiner: Vu, D.

Filed: 04/08/2004

Docket No.: TID-34937

Customer No.: 23494

Conf. No.: 2204

For: METHOD OF FABRICATING COMPLEMENTARY BIPOLAR TRANSISTORS  
WITH SiGe BASE REGIONS

## CERTIFICATION OF FACSIMILE TRANSMISSION

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Jacqueline J. Garner, Reg. No. 36,144November 15, 2005  
Date

## FACSIMILE COVER SHEET

<input checked="" type="checkbox"/> <b>FACSIMILE COVER SHEET</b>		<input checked="" type="checkbox"/> <b>AMENDMENT (7 Pages)</b>
<input type="checkbox"/> <b>NEW APPLICATION</b>		<input checked="" type="checkbox"/> <b>EOT 3mth (2 Pages)</b>
<input type="checkbox"/> <b>DECLARATION (# Pages)</b>		<input type="checkbox"/> <b>NOTICE OF APPEAL (# Pages)</b>
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<input type="checkbox"/> <b>CONTINUATION APP'N (# Pages)</b>		
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<b>NAME OF INVENTOR(S):</b> El-Kareh		<b>RECEIPT DATE &amp; SERIAL NO.:</b>  <b>Serial No.: 10/822,078</b> <b>Filing Date: 04/08/2004</b> <b>Conf. No.: 2204</b>
<b>TITLE OF INVENTION:</b> METHOD OF FABRICATING . . .		
<b>TI FILE NO.:</b> TI-34937	<b>DEPOSIT ACCT. NO.:</b> 20-0668	
<b>FAXED: 11/15/2005</b>		
<b>DUE: 8/18/2005</b>		
<b>ATTY/SEC'Y: JJG</b>		

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## AMENDMENT UNDER 37 CFR 1.111

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

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Trademark Office at (571) 273 - 8300 on 11/15/2005.  
Jacqueline J. Garner  
Reg. No. 36,144

Dear Sir:

The following amendments and remarks are offered in response to the Examiner's Office Action dated 05/18/2005. They are respectfully submitted as a full and complete response to that Action.

Please amend the above-referenced application as follows:

There are no **Amendments to the Specification**.**Amendments to the Claims** are reflected in the listing of claims that begin on page 2 of this paper.There are no **Amendments to the Drawings**.The **Remarks** begin on page 6.